SONY

ICX208AKB

1/4-inch CCD Image Sensor for NTSC Color Video Cameras

Description

The ICX208AKB is an interline CCD solid-state image sensor suitable for NTSC color video cameras. Compared with the current product ICX068AKB, sensitivity and saturation signal are improved drastically through the adoption of Super HAD CCD technology. High resolution is achieved through the use of Ye, Cy, Mg, and G complementary color mosaic filters.

This chip features a field period readout system and an electronic shutter with variable charge-storage time.

Also, this outline is miniaturized by using original package.

Features

- Maximum package dimensions:
 \$\phi8mm\$
- High sensitivity (+4dB compared with ICX068AKB)
- High saturation signal (+2.5dB compared with ICX068AKB)
- Horizontal register: 3.3 to 5.0V drive
- Reset gate: 3.3 to 5.0V drive
- No voltage adjustment (Reset gate and substrate bias are not adjusted.)
- High resolution, low smear and low dark current
- Excellent antiblooming characteristics
- · Continuous variable-speed shutter
- Recommended range of exit pupil distance: -20 to -100mm
- Ye, Cy, Mg, and G complementary color mosaic filters on chip

1/4-inch format

Silicon



- Interline CCD image sensor
- Optical size:
- Number of effective pixels: 768 (H) × 494
- Total number of pixels: 811
- Chip size:
- Unit cell size:
- Optical black:
- Number of dummy bits:

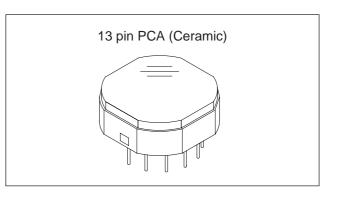
768 (H) \times 494 (V) approx. 380K pixels 811 (H) \times 508 (V) approx. 410K pixels 4.47mm (H) \times 3.80mm (V) 4.75µm (H) \times 5.55µm (V) Horizontal (H) direction: Front 3 pixels, rear 40 pixels Vertical (V) direction: Front 12 pixels, rear 2 pixels Horizontal 22 Vertical 1 (even fields only)

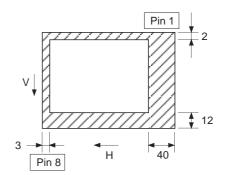
• Substrate material:



*Super HAD CCD is a trademark of Sony Corporation. Super HAD CCD is a CCD that drastically improves sensitivity by introducing newly developed semiconductor technology by Sony Corporation into Sony's high-performance HAD (Hole-Accumulation Diode) sensor.

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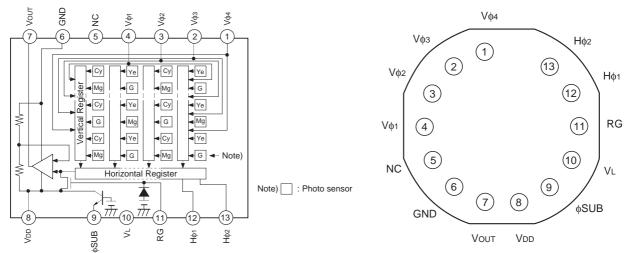




Optical black position (Top View)

Block Diagram and Pin Configuration

(Top View)



Pin Description

Pin No.	Symbol	Description	Pin No.	Symbol	Description
1	Vφ4	Vertical register transfer clock	8	Vdd	Supply voltage
2	Vфз	Vertical register transfer clock	9	φSUB	Substrate clock
3	Vφ2	Vertical register transfer clock	10	VL	Protective transistor bias
4	Vφ1	Vertical register transfer clock	11	RG	Reset gate clock
5	NC		12	Ηφ1	Horizontal register transfer clock
6	GND	GND	13	Ηφ2	Horizontal register transfer clock
7	Vout	Signal output			

Absolute Maximum Ratings

	Item	Ratings	Unit	Remarks
	Vdd, Vout, RG – ϕ SUB	-40 to +8	V	
	$V\phi_1, V\phi_3 - \phi SUB$	-50 to +15	V	
Against	$V\phi_2, V\phi_4, VL - \phi SUB$	-50 to +0.3	V	
	Hφ1, Hφ2, GND – φSUB	-40 to +0.3	V	
	Vdd, Vout, RG – GND	-0.3 to +18	V	
Against GND	$V\phi_1, V\phi_2, V\phi_3, V\phi_4 - GND$	-10 to +18	V	
	$H\phi_1, H\phi_2 - GND$	-10 to +5	V	
	Vφ1, Vφ3 – VL	-0.3 to +28	V	
Against V∟	Vφ2, Vφ4, Hφ1, Hφ2, GND – VL	-0.3 to +15	V	
	Voltage difference between vertical clock input pins	to +15	V	*1
Between input clock pins	Ηφ1 - Ηφ2	-5 to +5	V	
	$H\phi_1, H\phi_2 - V\phi_4$	-13 to +13	V	
Storage temperature		-30 to +80	°C	
Operating temperature)	-10 to +60	°C	

^{*1} +24V (Max.) when clock width < 10μ s, clock duty factor < 0.1%.

Bias Conditions

Item	Symbol	Min.	Тур.	Max.	Unit	Remarks
Supply voltage	Vdd	14.55	15.0	15.45	V	
Protective transistor bias	VL		*1	•		
Substrate clock	φSUB		*2			
Reset gate clock	φRG		*2			

*1 VL setting is the VvL voltage of the vertical transfer clock waveform, or the same power supply as the VL power supply for the V driver should be used.

*2 Do not apply a DC bias to the substrate clock and reset gate clock pins, because a DC bias is generated within the CCD.

DC Characteristics

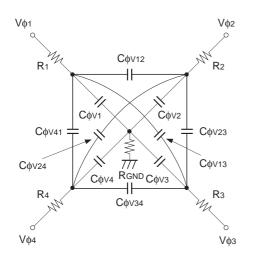
Item	Symbol	Min.	Тур.	Max.	Unit	Remarks
Supply current	Idd		4.5	6.5	mA	

Clock Voltage Conditions

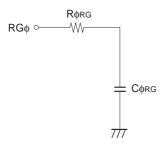
Item	Symbol	Min.	Тур.	Max.	Unit	Waveform diagram	Remarks
Readout clock voltage	Vvт	14.55	15.0	15.45	V	1	
	Vvh1, Vvh2	-0.05	0	0.05	V	2	Vvн = (Vvн1 + Vvн2)/2
	Vvнз, Vvн4	-0.2	0	0.05	V	2	
	Vvl1, Vvl2, Vvl3, Vvl4	-8.0	-7.0	-6.5	V	2	Vvl = (Vvl3 + Vvl4)/2
	Vφv	6.3	7.0	8.05	V	2	$V\phi = V + n - V + n (n = 1 \text{ to } 4)$
Vertical transfer clock	Vvнз — Vvн	-0.25		0.1	V	2	
voltage	Vvн4 — Vvн	-0.25		0.1	V	2	
	V∨нн			0.3	V	2	High-level coupling
	Vvhl			0.3	V	2	High-level coupling
	Vvlh			0.3	V	2	Low-level coupling
	Vvll			0.3	V	2	Low-level coupling
Horizontal transfer	Vфн	3.0	3.3	5.25	V	3	
clock voltage	Vhl	-0.05	0	0.05	V	3	
Reset gate clock	Vørg	3.0	3.3	5.5	V	4	Input through 0.1µF capacitance
voltage	Vrglh – Vrgll			0.4	V	4	Low-level coupling
	Vrgl – Vrglm			0.5	V	4	Low-level coupling
Substrate clock voltage	Vфsuв	21.0	22.0	23.5	V	5	

Clock Equivalent Circuit Constant

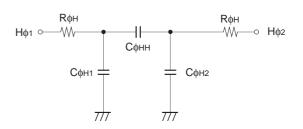
Item	Symbol	Min.	Тур.	Max.	Unit	Remarks
Capacitance between vertical transfer	Cφν1, Cφν3		680		pF	
clock and GND	C φv2, C φv4		470		pF	
	C φV12, C φV34		330		pF	
Capacitance between vertical transfer	C φV23, C φV41		270		pF	
clocks	СфV13		82		pF	
	СфV24		75		pF	
Capacitance between horizontal transfer clock and GND	Сфн1, Сфн2		47		pF	
Capacitance between horizontal transfer clocks	Сфнн		47		pF	
Capacitance between reset gate clock and GND	Cørg		5		pF	
Capacitance between substrate clock and GND	Сфѕив		180		pF	
Vertical transfer clock series resistor	R1, R2, R3, R4		82		Ω	
Vertical transfer clock ground resistor	Rgnd		15		Ω	
Horizontal transfer clock series resistor	Rфн		12		Ω	
Reset gate clock series resistor	Rørg		39		Ω	



Vertical transfer clock equivalent circuit



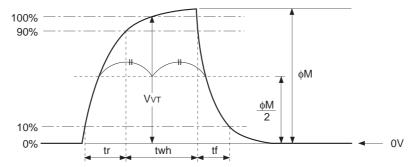
Reset gate clock equivalent circuit



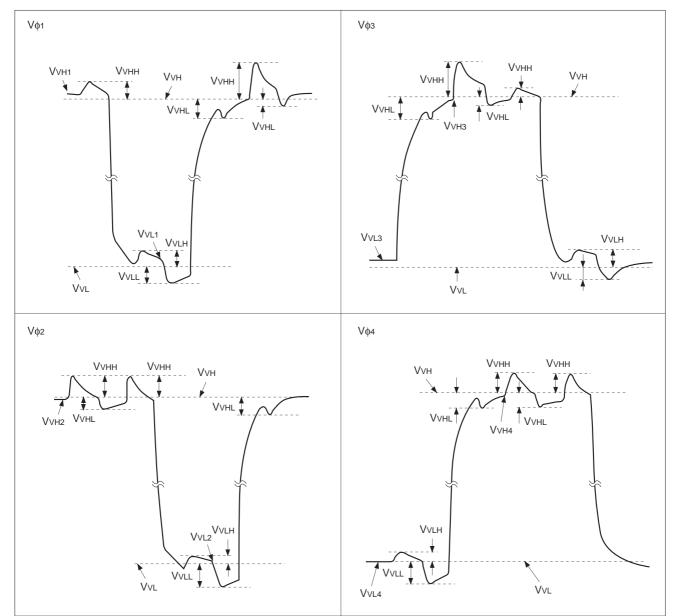
Horizontal transfer clock equivalent circuit

Drive Clock Waveform Conditions

(1) Readout clock waveform

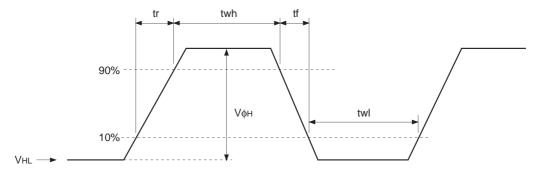




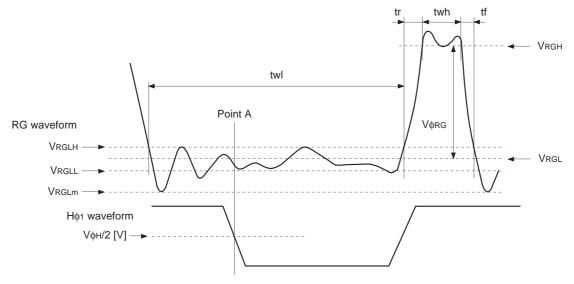


 $V_{VH} = (V_{VH1} + V_{VH2})/2$ $V_{VL} = (V_{VL3} + V_{VL4})/2$ $V_{\varphi V} = V_{VHN} - V_{VLN} (n = 1 \text{ to } 4)$

(3) Horizontal transfer clock waveform



(4) Reset gate clock waveform



VRGLH is the maximum value and VRGLL is the minimum value of the coupling waveform during the period from Point A in the above diagram until the rising edge of RG. In addition, VRGL is the average value of VRGLH and VRGLL.

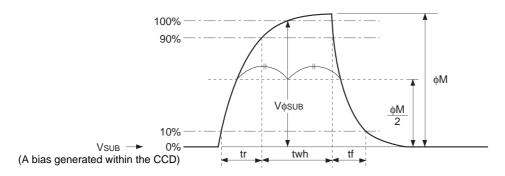
VRGL = (VRGLH + VRGLL)/2

Assuming VRGH is the minimum value during the interval twh, then:

 $V\phi rg = Vrgh - Vrgl$

Negative overshoot level during the falling edge of RG is VRGLm.

(5) Substrate clock waveform



Clock Switching	Characteristics
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ltem		Symbol		twh			twl		tr			tf		Unit	Remarks	
	nem	Symbol	Min.	Тур.	Max.	Unit	Remarks									
Rea	dout clock	Vт	2.3	2.5						0.5			0.5		μs	During readout
Vert cloc	ical transfer k	Vφ1, Vφ2, Vφ3, Vφ4										15		250	ns	*1
<u> </u>	During	Hφ1	26	28.5		26	28.5			6.5	9.5		6.5	9.5	ns	*2
onta r clo	imaging	Hø2	26	28.5		26	28.5			6.5	9.5		6.5	9.5	113	
Horizontal transfer clock	During parallel-serial	Hφ1		5.38						0.01			0.01			
tral	conversion	Hø2					5.38			0.01			0.01		μs	
Res	et gate clock	φRG	11	13			51			3			3		ns	
Sub	strate clock	фSUB	1.5	1.8							0.5			0.5	μs	During drain charge

*1 When vertical transfer clock driver CXD1267AN is used.

*2 When $V\phi_H = 3.0V$. tf \geq tr - 2ns, and the cross-point voltage (VCR) for the H ϕ_1 rising side of the H ϕ_1 and H ϕ_2 waveforms must be at least V $\phi_H/2$ [V].

Item	Symbol		two	Unit	Remarks		
	Symbol	Min.	Тур.	Max.	Unit	Remarks	
Horizontal transfer clock	Ηφ1, Ηφ2	22	26		ns	*3	

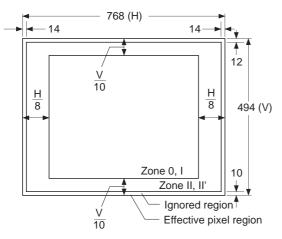
*3 The overlap period for twh and twl of horizontal transfer clocks H ϕ_1 and H ϕ_2 is two.

Image Sensor Characteristics

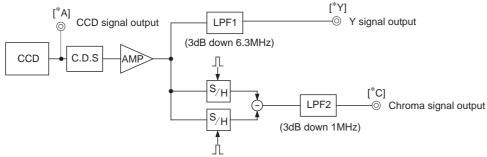
(Ta	= 25°	C)

Item	Symbol	Min.	Тур.	Max.	Unit	Measurement method	Remarks
Sensitivity	S	360	450		mV	1	
Constitute rotio	RмgG	0.93		1.35		2	
Sensitivity ratio	RYeCy	1.15		1.48		2	
Saturation signal	Ysat	800			mV	3	Ta = 60°C
Smear	Sm		0.009	0.015	%	4	
Video circol choding	OLIV			20	%	5	Zone 0 and I
Video signal shading	SHy			25	%	5	Zone 0 to II'
Uniformity between video	ΔSr			10	%	6	
signal channels	ΔSb			10	%	6	
Dark signal	Ydt			2	mV	7	Ta = 60°C
Dark signal shading	ΔYdt			1	mV	8	Ta = 60°C
Flicker Y	Fy			2	%	9	
Flicker R-Y	Fcr			5	%	9	
Flicker B-Y	Fcb			5	%	9	
Line crawl R	Lcr			3	%	10	
Line crawl G	Lcg			3	%	10	
Line crawl B	Lcb			3	%	10	
Line crawl W	Lcw			3	%	10	
Lag	Lag			0.5	%	11	

Zone Definition of Video Signal Shading



Measurement System

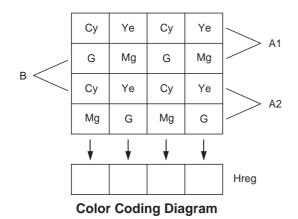


Note) Adjust the amplifier gain so that the gain between [*A] and [*Y], and between [*A] and [*C] equals 1.

Image Sensor Characteristics Measurement Method

O Measurement conditions

- 1) In the following measurements, the device drive conditions are at the typical values of the bias and clock voltage conditions.
- 2) In the following measurements, spot blemishes are excluded and, unless otherwise specified, the optical black level (OB) is used as the reference for the signal output, which is taken as the value of Y signal output or chroma signal output of the measurement system.
- © Color coding of this image sensor & Composition of luminance (Y) and chroma (color difference) signals



As shown in the left figure, fields are read out. The charge is mixed by pairs such as A1 and A2 in the A field. (pairs such as B in the B field)

As a result, the sequence of charges output as signals from the horizontal shift register (Hreg) is, for line A1, (G + Cy), (Mg + Ye), (G + Cy), and (Mg + Ye).

These signals are processed to form the Y signal and chroma (color difference) signal. The Y signal is formed by adding adjacent signals, and the chroma signal is formed by subtracting adjacent signals. In other words, the approximation:

$$Y = \{(G + Cy) + (Mg + Ye)\} \times 1/2$$

is used for the Y signal, and the approximation:

$$R - Y = \{(Mg + Ye) - (G + Cy)\}\$$

= {2R - G}

is used for the chroma (color difference) signal. For line A2, the signals output from Hreg in sequence are

$$Mg + Cy), (G + Ye), (Mg + Cy), (G + Ye)$$

The Y signal is formed from these signals as follows:

 $Y = {(G + Ye) + (Mg + Cy)} \times 1/2$

This is balanced since it is formed in the same way as for line A1.

In a like manner, the chroma (color difference) signal is approximated as follows:

$$-(B - Y) = {(G + Ye) - (Mg + Cy)}$$

= - {2B - G}

In other words, the chroma signal can be retrieved according to the sequence of lines from R - Y and - (B - Y) in alternation. This is also true for the B field.

◎ Definition of standard imaging conditions

1) Standard imaging condition I:

Use a pattern box (luminance 706cd/m², color temperature of 3200K halogen source) as a subject. (Pattern for evaluation is not applicable.) Use a testing standard lens with CM500S (t = 1.0mm) as an IR cut filter and image at F5.6. The luminous intensity to the sensor receiving surface at this point is defined as the standard sensitivity testing luminous intensity.

2) Standard imaging condition II:

Image a light source (color temperature of 3200K) with a uniformity of brightness within 2% at all angles. Use a testing standard lens with CM500S (t = 1.0mm) as an IR cut filter. The luminous intensity is adjusted to the value indicated in each testing item by the lens diaphragm.

3) Standard imaging condition III:

Image a light source (color temperature of 3200K) with a uniformity of brightness within 2% at all angles. Use a testing standard lens (exit pupil distance -33mm) with CM500S (t = 1.0mm) as an IR cut filter. The luminous intensity is adjusted to the value indicated in each testing item by the lens diaphragm.

1. Sensitivity

Set to standard imaging condition I. After selecting the electronic shutter mode with a shutter speed of 1/250s, measure the Y signal (Ys) at the center of the screen and substitute the value into the following formula.

$$S = Ys \times \frac{250}{60} \text{ [mV]}$$

2. Sensitivity ratio

Set to standard imaging condition II. Adjust the luminous intensity so that the average value of the Y signal output is 200mV, and then measure the Mg signal output (S_{Mg} [mV]) and G signal output (S_{G} [mV]), and Ye signal output (S_{Ye} [mV]) and Cy signal output (S_{Cy} [mV]) at the center of the screen with frame readout method. Substitute the values into the following formula.

 $R_{MgG} = S_{Mg}/S_G$ $R_{YeCy} = S_{Ye}/S_{Cy}$

3. Saturation signal

Set to standard imaging condition II. After adjusting the luminous intensity to 10 times the intensity with average value of the Y signal output, 200mV, measure the minimum value of the Y signal.

4. Smear

Set to standard imaging condition II. With the lens diaphragm at F5.6 to F8, adjust the luminous intensity to 500 times the intensity with average value of the Y signal output, 200mV. When the readout clock is stopped and the charge drain is executed by the electronic shutter at the respective H blankings, measure the maximum value YSm [mV] of the Y signal output and substitute the value into the following formula.

$$Sm = \frac{YSm}{200} \times \frac{1}{500} \times \frac{1}{10} \times 100 \, [\%] \, (1/10V \text{ method conversion value})$$

5. Video signal shading

Set to standard imaging condition III. With the lens diaphragm at F5.6 to F8, adjust the luminous intensity so that the average value of the Y signal output is 200mV. Then measure the maximum (Ymax [mV]) and minimum (Ymin [mV]) values of the Y signal and substitute the values into the following formula.

 $SHy = (Ymax - Ymin)/200 \times 100 [\%]$

6. Uniformity between video signal channels

Set to standard imaging condition II. Adjust the luminous intensity so that the average value of the Y signal output is 200 mV, and then measure the maximum (Crmax, Cbmax [mV]) and minimum (Crmin, Cbmin [mV]) values of the R – Y and B – Y channels of the chroma signal and substitute the values into the following formula.

 $\Delta Sr = | (Crmax - Crmin)/200 | \times 100 [\%]$ $\Delta Sb = | (Cbmax - Cbmin)/200 | \times 100 [\%]$

7. Dark signal

Measure the average value of the Y signal output (Ydt [mV]) with the device ambient temperature 60°C and the device in the light-obstructed state, using the horizontal idle transfer level as a reference.

8. Dark signal shading

After measuring 7, measure the maximum (Ydmax [mV]) and minimum (Ydmin [mV]) values of the Y signal output and substitute the values into the following formula.

 Δ Ydt = Ydmax – Ydmin [mV]

9. Flicker

1) Fy

Set to standard imaging condition II. Adjust the luminous intensity so that the average value of the Y signal output is 200mV, and then measure the difference in the signal level between fields (Δ Yf [mV]). Then substitute the value into the following formula.

$$Fy = (\Delta Y f/200) \times 100 [\%]$$

2) Fcr, Fcb

Set to standard imaging condition II. Adjust the luminous intensity so that the average value of the Y signal output is 200mV, insert an R or B filter, and then measure both the difference in the signal level between fields of the chroma signal (Δ Cr, Δ Cb) as well as the average value of the chroma signal output (CAr, CAb). Substitute the values into the following formula.

 $Fci = (\Delta Ci/CAi) \times 100 [\%] (i = r, b)$

10. Line crawls

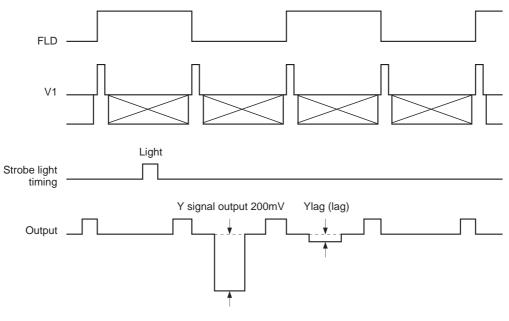
Set to standard imaging condition II. Adjust the luminous intensity so that the average value of the Y signal output is 200mV, and then insert a white subject and R, G, and B filters and measure the difference between Y signal lines for the same field (Δ YIw, Δ YIr, Δ YIg, Δ YIb [mV]). Substitute the values into the following formula.

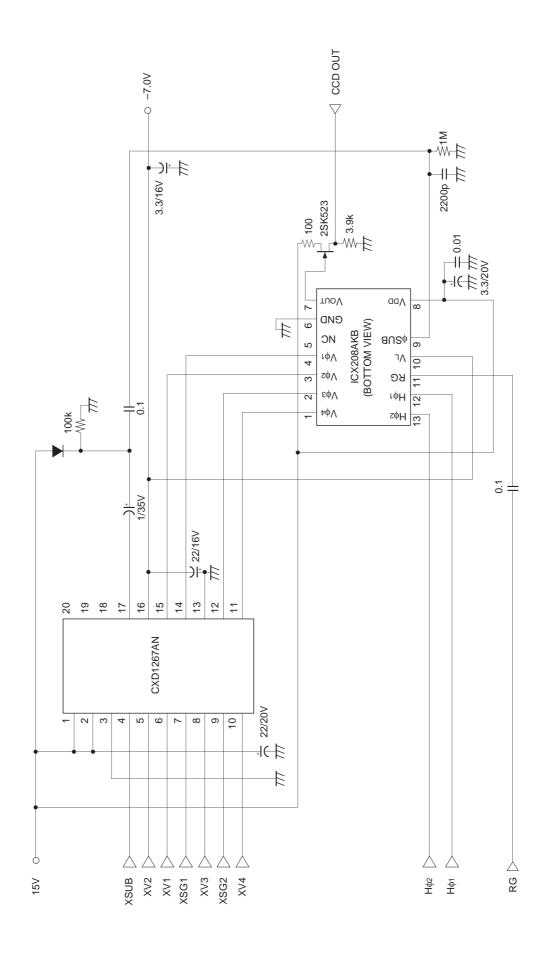
 $Lci = (\Delta Y li/200) \times 100 [\%] (i = w, r, g, b)$

11. Lag

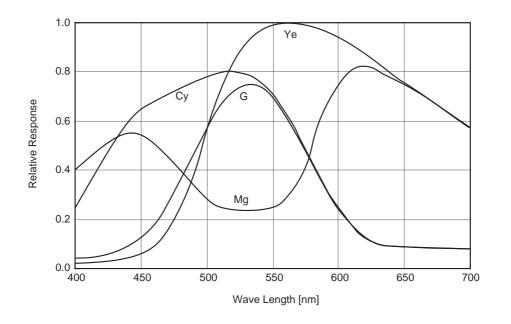
Adjust the Y signal output value generated by strobe light to 200mV. After setting the strobe light so that it strobes with the following timing, measure the residual signal (Ylag). Substitute the value into the following formula.

Lag = (Ylag/200) × 100 [%]



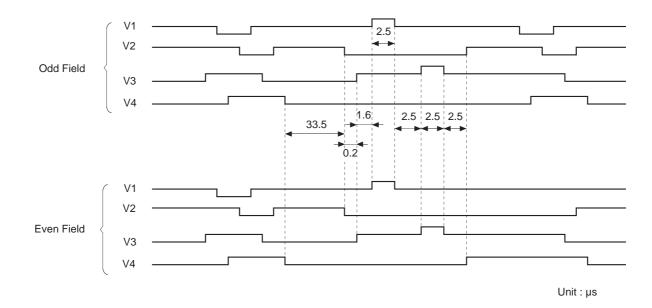


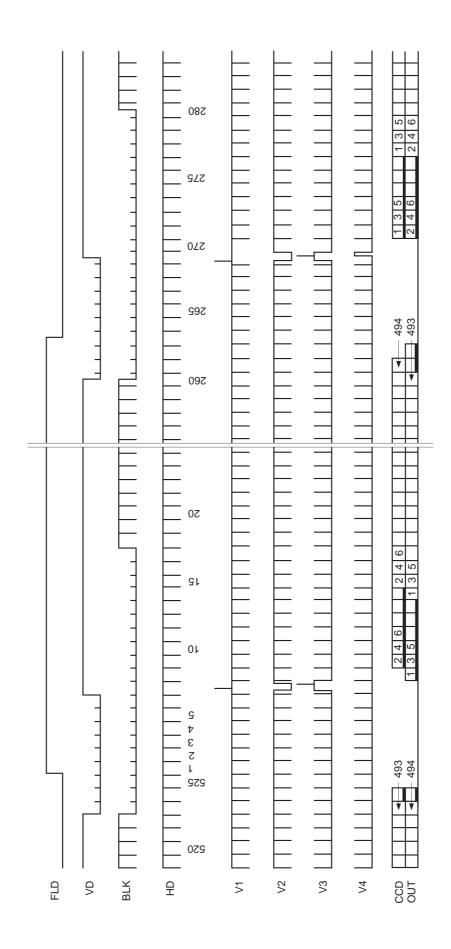
Drive Circuit



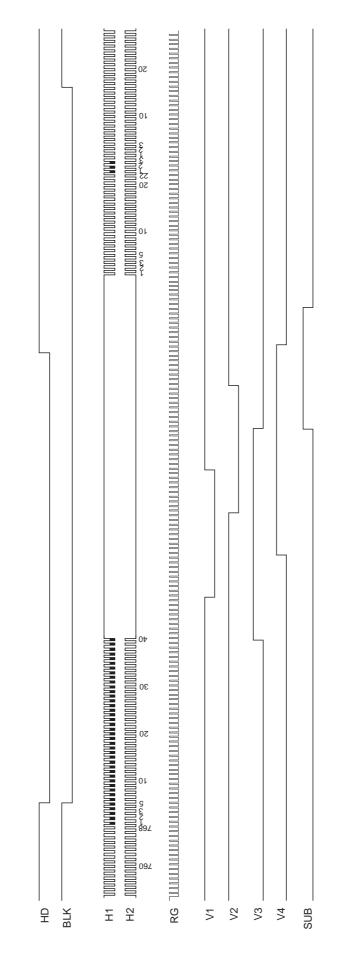
Spectral Sensitivity Characteristics (excludes both lens characteristics and light source characteristics)

Sensor Readout Clock Timing Chart





Drive Timing Chart (Vertical Sync)



Notes on Handling

1) Static charge prevention

CCD image sensors are easily damaged by static discharge. Before handling be sure to take the following protective measures.

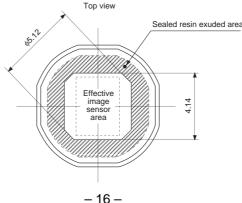
- a) Either handle bare handed or use non-chargeable gloves, clothes or material. Also use conductive shoes.
- b) When handling directly use an earth band.
- c) Install a conductive mat on the floor or working table to prevent the generation of static electricity.
- d) Ionized air is recommended for discharge when handling CCD image sensor.
- e) For the shipment of mounted substrates, use boxes treated for the prevention of static charges.

2) Soldering

- a) Make sure the package temperature does not exceed 80°C.
- b) Solder dipping in a mounting furnace causes damage to the glass and other defects. Use a ground 30W soldering iron and solder each pin in less than 2 seconds. For repairs and remount, cool sufficiently.
- c) To dismount an image sensor, do not use a solder suction equipment. When using an electric desoldering tool, use a thermal controller of the zero cross On/Off type and connect it to ground.
- 3) Dust and dirt protection

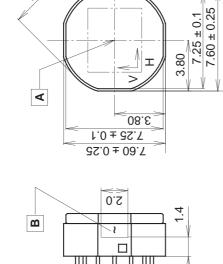
Image sensors are packed and delivered by taking care of protecting its glass plates from harmful dust and dirt. Clean glass plates with the following operation as required, and use them.

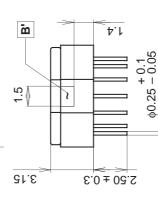
- a) Operate in clean environments (around class 1000 is appropriate).
- b) Do not either touch glass plates by hand or have any object come in contact with glass surfaces. Should dirt stick to a glass surface, blow it off with an air blower. (For dirt stuck through static electricity ionized air is recommended.)
- c) Clean with a cotton bud and ethyl alcohol if the grease stained. Be careful not to scratch the glass.
- d) Keep in a case to protect from dust and dirt. To prevent dew condensation, preheat or precool when moving to a room with great temperature differences.
- e) When a protective tape is applied before shipping, just before use remove the tape applied for electrostatic protection. Do not reuse the tape.
- 4) Do not expose to strong light (sun rays) for long periods, color filters will be discolored. When high luminance objects are imaged with the exposure level control by electronic-iris, the luminance of the image-plane may become excessive and discolor of the color filter will possibly be accelerated. In such a case, it is advisable that taking-lens with the automatic-iris and closing of the shutter during the power-off mode should be properly arranged. For continuous using under cruel condition exceeding the normal using condition, consult our company.
- 5) Exposure to high temperature or humidity will affect the characteristics. Accordingly avoid storage or usage in such conditions.
- 6) CCD image sensors are precise optical equipment that should not be subject to too much mechanical shocks.
- 7) Eclipse (to get dark around the four corners of the picture) may occur when some object lenses are in the open iris state.





88.00×0.25



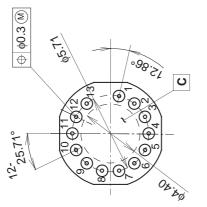


TURE	Ceramic	GOLD PLATIN	Fe-Ni-Co Alloy
PACKAGE STRUCTURE	PACKAGE MATERIAL	LEAD TREATMENT	LEAD MATERIAL

ġ

0.4g

PACKAGE WEIGHT



- 1. "A" is the center of the effective image area.
- The point "B" of the package is the horizontal reference.
 The point "B" of the package is the vertical reference.
- 3. The bottom "C" of the package is the height reference.
- 4. The center of the effective image area relative to the center of the package (*) is (H, V) = (0, 0) \pm 0.15mm.
- 5. The rotation angle of the effective image area relative to H and V is $\pm 1^{\circ}$.
- 6. The height from the bottom "C" to the effective image area is 1.44 ± 0.15 mm.
- 7. The tilt of the effective image area relative to the bottom "C" is less than 60µm.
- 8. The thickness of the cover glass is 0.75mm, and the refractive index is 1.5.
- * Center of the package: The center is halfway between two pairs of opposite sides, as measured from "B", "B"".